NSN 5961-00-945-2793

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View Online at https://aerobasegroup.com/nsn/5961-00-945-2793 **Inclosure Material:** Metal **Overall Length:** 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To0-59 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 8.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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